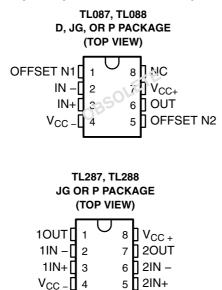
The TL087, TL088, and TL287 are obsolete and are no longer supplied.

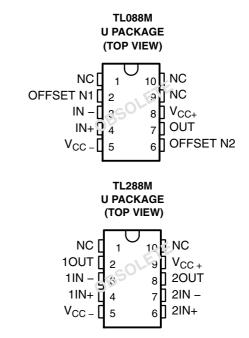
SLOS082B - MARCH 1979 REVISED - JULY 2004

- Low Input Offset Voltage . . . 0.5 mV Max
- Low Power Consumption
- Wide Common-Mode and Differential Voltage Ranges
- Low Input Bias and Offset Currents
- High Input Impedance . . . JFET-Input Stage



NC - No internal connection

- Internal Frequency Compensation
- Latch-Up-Free Operation
- High Slew Rate . . . 18 V/μs Typ
- Low Total Harmonic Distortion 0.003% Typ



description/ordering information

These JFET-input operational amplifiers incorporate well-matched high-voltage JFET and bipolar transistors in a monolithic integrated circuit. They feature low input offset voltage, high slew rate, low input bias and offset currents, and low temperature coefficient of input offset voltage. Offset-voltage adjustment is provided for the TL087 and TL088.

The C-suffix devices are characterized for operation from 0° C to 70° C, and the I-suffix devices are characterized for operation from -40° C to 85° C. The M-suffix devices are characterized for operation over the full military temperature range of -55° C to 125° C.

ORDERING INFORMATION

T _A	TYPE	V _{IO} MAX AT 25°C	PACKAGE†		ORDERABLE PART NUMBER	TOP-SIDE MARKING
0°C to 70°C	Dual	1 mV	PDIP (P)	Tube of 50	TL288CP	TL288CP

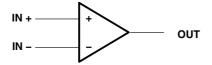
[†] Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



symbol (each amplifier)



absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

		TL088M TL288M	TL087I TL088I TL287I TL288I	TL087C TL088C TL287C TL288C	UNIT
Supply voltage, VCC+ (see Note 1)		18	18	18	V
Supply voltage, V _{CC} – (see Note 1)		-18	-18	-18	V
Differential input voltage (see Note 2)		±30	±30	±30	V
Input voltage (see Notes 1 and 3)		±15	±15	±15	V
Input current, I _I (each Input)	±1	±1	±1	mA	
Output current, IO (each output)		±80	±80	±80	mA
Total V _{CC} + terminal current		160	160	160	mA
Total V _{CC} - terminal current		-160	-160	-160	mA
Duration of output short circuit (see Note 4)		Unlimited	Unlimited	Unlimited	
Continuous total dissipation		Ş	See Dissipation R	ating Table	
Maximum junction temperature, T _J			150	150	°C
Package thermal impedance, θ _{JA} (see Notes 5 and 6)	P package		85	85	°C/W
Lead temperature 1,6 mm (1/16 inch) from case for 60 seconds	JG or U package	300	300	300	°C
Storage temperature range, T _{stg}		-65 to 150	-65 to 150	-65 to 150	°C

- NOTES: 1. All voltage values, except differential voltages, are with respect to the midpoint between V_{CC+} and V_{CC-} .
 - 2. Differential voltages are at the noninverting input terminal with respect to the inverting input terminal.
 - 3. The magnitude of the input voltage must never exceed the magnitude of the supply voltage or 15 V, whichever is less.
 - 4. The output may be shorted to ground or to either supply. Temperature and/or supply voltages must be limited to ensure that the dissipation rating is not exceeded.
 - 5. Maximum power dissipation is a function of $T_J(max)$, θ_{JA} , and T_A . The maximum allowable power dissipation at any allowable ambient temperature is PD = $(T_J(max) T_A)/\theta_{JA}$. Operating at the absolute maximum T_J of 150°C can affect reliability.
 - 6. The package thermal impedance is calculated in accordance with JESD 51-7.
 - 7. The output may be shorted to ground or to either supply. Temperature and/or supply voltages must be limited to ensure that the dissipation rating is not exceeded.
 - 8. Maximum power dissipation is a function of $T_J(max)$, θ_{JA} , and T_A . The maximum allowable power dissipation at any allowable ambient temperature is PD = $(T_J(max) T_A)/\theta_{JA}$. Operating at the absolute maximum T_J of 150°C can affect reliability.
 - 9. The package thermal impedance is calculated in accordance with JESD 51-7.

DISSIPATION RATING TABLE

PACKAGE	$T_A \le 25^{\circ}C$ POWER RATING	DERATING FACTOR ABOVE T _{A =} 25°C	T _A = 70°C POWER RATING	T _A = 85°C POWER RATING	T _A = 125°C POWER RATING
JG	1050 mW	8.4 mW/°C	672 mW	546 mW	210 mW
U	675 mW	5.4 mW/°C	432 mW	351 mW	135 mW

TL087, TL088, TL287, TL288 JFET-INPUT OPERATIONAL AMPLIFIERS

The TL087, TL088, and TL287 are obsolete and are no longer supplied.

SLOS082B - MARCH 1979 REVISED - JULY 2004

recommended operating conditions

			C-SU	FFIX	I-SUF	FIX	M-SU	FFIX	UNIT
			MIN	MAX	MIN	MAX	MIN	MAX	UNIT
V _{CC}	Supply voltage		±5	±5	±5	±5	±5	±15	V
.,		$V_{CC\pm} = \pm 5 \text{ V}$	-1	4	-1	4	-1	4	.,
V _{IC}	Common-mode input voltage	$V_{CC\pm} = \pm 15 \text{ V}$	-11	11	-11	11	-11	11	V
,,	la and malle an	$V_{CC\pm} = \pm 5 \text{ V}$	-1	4	-1	4	-1	4	
V _I	Input voltage	$V_{CC\pm} = \pm 15 \text{ V}$	-11	11	-11	11	-11	11	V
T _A	Operating free-air temperature		0	70	-40	85	-55	125	°C

operating characteristics $V_{CC}=\pm 15$ V, T_{A} = $25^{\circ}C$

PARAMETER		TEST CONDITIONS			8M, TL2	88M	TL087I, TL087C TL088I, TL088C			UNIT
				MIN	MIN TYP MAX MIN TYP MA		MAX			
SR	Slew rate at unity gain	V _I = 10 V, C _L = 100 pF,	$R_L = 2 k\Omega$, $A_{VD} = 1$		18		8	18		V/μs
t _r	Rise time	V _I = 20 mV,	$R_L = 2 k\Omega$,		55			55		ns
	Overshoot factor	$C_L = 100 pF,$	$A_{VD} = 1$		25			25		%
V_n	Equivalent input noise voltage	$R_S = 100 \Omega$,	f = 1 kHz		19			19		nV/√ Hz

SLOS082B - MARCH 1979 - REVISED - JULY 2004

electrical characteristics, $V_{CC^{\pm}} = \pm 15 \text{ V}$

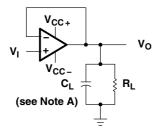
	PARAMETER	AMETER TEST CONDITIONS†			L088M L288M			TL087I TL088I TL287I TL288I		T T	L087C L088C L287C L288C		UNIT
				MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	!
		$R_S = 50 \Omega$,	TL087, TL287					0.1	0.5		0.1	0.5	
V	land offer trade	$V_O = 0$ $T_A = 25^{\circ}C$	TL088, TL288		0.1	3		0.1	1		0.1	1	
V_{IO}	Input offset voltage	$R_S = 50 \Omega$,	TL087, TL287						2			1.5	mV
	$V_O = 0$, $T_A = \text{full range}$	TL088, TL288			6			3			2.5		
lpha VIO	Temperature coefficient of input offset voltage	$R_S = 50 \Omega$,	T _A = 25°C to MAX		10			8			8		μV/°C
	Innut offset surrent	T _A = 25°C			5			5	100		5	100	pА
I _{IO}	Input offset current	T _A = full range				25			3			2	nA
I _{IB}	Input bias current‡	T _A = 25°C			30			30	200		30	200	pА
		T _A = full range				100			20			7	nA
V_{ICR}	Common-mode input voltage range	T _A = 25°C		(V _{CC} ₋) t (V _{CC} ₊)	0		(V _{CC} -)	to		(V _{CC} -) to (V _{CC} +)			V
		T _A = 25°C,	$R_L = 10 \text{ k}\Omega$	24	27		24	27		24	27		
$V_{O(PP)}$	Maximum-peak-to-peak output voltage swing	T 6.11	$R_L \ge 10 \text{ k}\Omega$	24			24			24			V
, ,	output voltage swilig	T _A = full range	$R_L \ge 2 \ k\Omega$	20			20			20			!
^	Large-signal differential	$R_L \ge 2 \text{ k}\Omega,$ $T_A = 25^{\circ}\text{C}$	$V_{O} = \pm 10 \text{ V},$	50	105		50	105		50	105		V/mV
A _{VD}	voltage amplification	$R_L \ge 2 \text{ k}\Omega,$ $T_A = \text{full range}$	$V_{O} = \pm 10 \text{ V},$	25			25			25			V/IIIV
B ₁	Unity-gain bandwidth	T _A = 25°C			3			3			3		MHz
rį	Input resistance	T _A = 25°C			10 ¹²			10 ¹²			10 ¹²		Ω
CMRR	Common–mode rejection ratio	$V_{IC} = V_{ICR}$ min,		80	93		80	93		80	93		dB
k _{SVR}	Supply voltage rejection ratio ($\Delta V_{CC} \pm \Delta V_{IO}$)	$R_S = 50 \Omega$, $V_{CC\pm} = \pm 9 V \text{ to}$ $T_A = 25^{\circ}\text{C}$	- ·	80	99		80	99		80	99		dB
Icc	Supply current (per amplifier)	No load, T _A = 25°C	$V_O = 0 V$,		26	2.8		2.6	2.8		2.6	2.8	mA

[†] All characteristics are measured under open–loop conditions with zero common-mode input voltage, unless otherwise specified. Full range for T_A is –55°C to 125°C for TL_88M; –40°C to 85°C for TL_8_I; and 0°C to 70°C for TL_8_C.



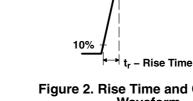
[‡] Input bias currents of an FET-input operational amplifier are normal junction reverse currents, which are temperature sensitive. Pulse techniques must be used that will maintain the junction temperature as close to the ambient temperature as possible.

PARAMETER MEASUREMENT INFORMATION



NOTE A: C_L includes fixture capacitance.

Figure 1. Slew Rate, Rise/Fall Time, and Overshoot Test Circuit



Overshoot

Figure 2. Rise Time and Overshoot Waveform

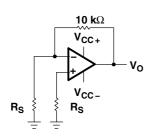
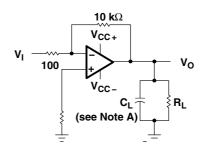


Figure 3. Noise Voltage Test Circuit



NOTE A: C_L includes fixture capacitance.

Figure 4. Unity-Gain Brandwidth and Phase Margin Test Circuit

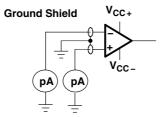


Figure 5. Input Bias and Offset **Current Test Circuit**

TL087, TL088, TL287, TL288 JFET-INPUT OPERATIONAL AMPLIFIERS

SLOS082B - MARCH 1979 - REVISED - JULY 2004

typical values

Typical values as presented in this data sheet represent the median (50% point) of device parametric performance.

input bias and offset current

At the picoamp bias current level typical of these JFET operational amplifiers, accurate measurement of the bias current becomes difficult. Not only does this measurement require a picoammeter, but test socket leakages can easily exceed the actual device bias currents. To accurately measure these small currents, Texas Instruments uses a two-step process. The socket leakage is measured using picoammeters with bias voltages applied, but with no device in the socket. The device then is inserted in the socket and a second test that measures both the socket leakage and the device input bias current is performed. The two measurements then are subtracted algebraically to determine the bias current of the device.



TYPICAL CHARACTERISTICS

table of graphs

			FIGURE
αVIO	Temperature coefficient of input offset voltage	Distribution	6, 7
I _{IO}	Input offset current	vs Temperature	8
I _{IB}	Input bias current	vs V _{IC} vs Temperature	9 8
VI	Common-mode input voltage range limits	vs V _{CC} vs Temperature	10 11
V_{ID}	Differential input voltage	vs Output voltage	12
V _{OM}	Maximum peak output voltage swing	vs V _{CC} vs Output current vs Frequency vs Temperature	13 17 14, 15, 16 18
A _{VD}	Differential voltage amplification	vs R _L vs Frequency vs Temperature	19 20 21
z _o	Output impedance	vs Frequency	24
CMRR	Common-mode rejection ratio	vs Frequency vs Temperature	22 23
k _{SVR}	Supply-voltage rejection ratio	vs Temperature	25
I _{OS}	Short-circuit output current	vs V _{CC} vs Time vs Temperature	26 27 28
I _{CC}	Supply current	vs V _{CC} vs Temperature	29 30
SR	Slew rate	vs R _L vs Temperature	31 32
	Overshoot factor	vs C _L	33
V _n	Equivalent input noise voltage	vs Frequency	34
THD	Total harmonic distortion	vs Frequency	35
B ₁	Unity-gain bandwidth	vs V _{CC} vs Temperature	36 37
φ _m	Phase margin	vs V _{CC} vs C _L vs Temperature	38 39 40
	Phase shift	vs Frequency	20
	Pulse response	Small-signal Large-signal	41 42

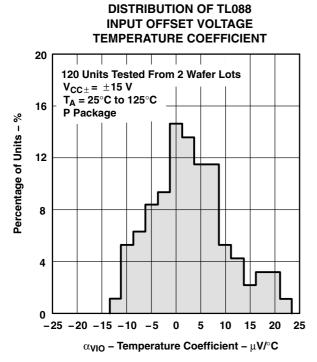
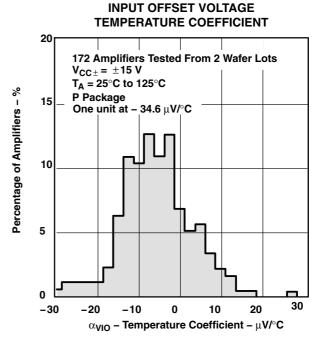


Figure 6



DISTRIBUTION OF TL288

Figure 7



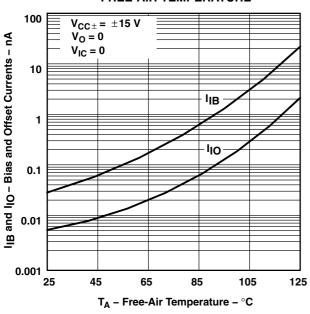


Figure 8

INPUT BIAS CURRENT COMMON-MODE INPUT VOLTAGE

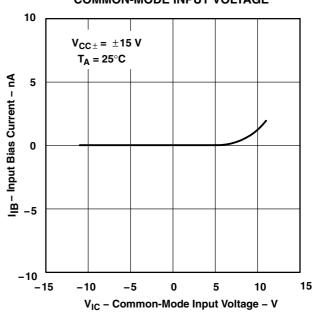


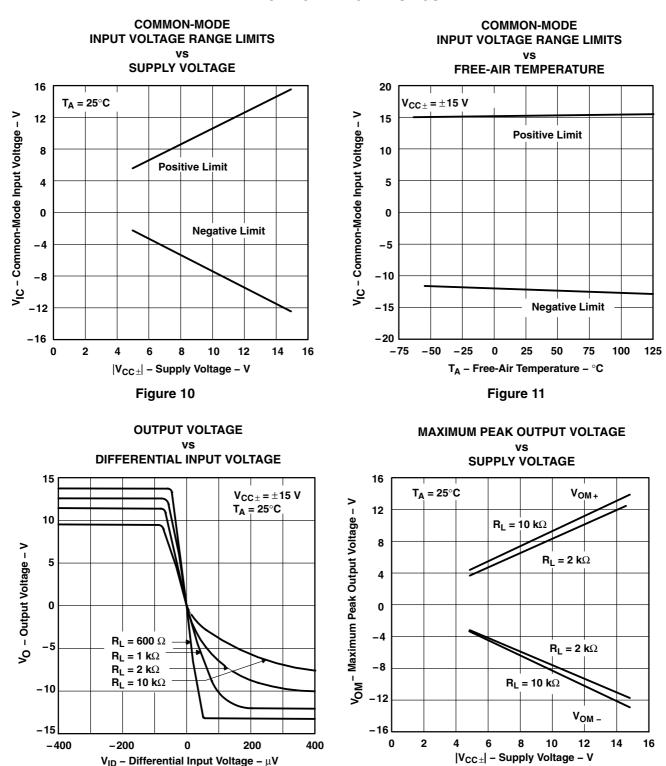
Figure 9

[†] Data at high and low temperatures are applicable within the rated operating free-air temperature ranges of the various devices.



Figure 13

TYPICAL CHARACTERISTICS[†]



[†] Data at high and low temperatures are applicable within the rated operating free-air temperature ranges of the various devices.

Figure 12



MAXIMUM PEAK-TO-PEAK OUTPUT VOLTAGE

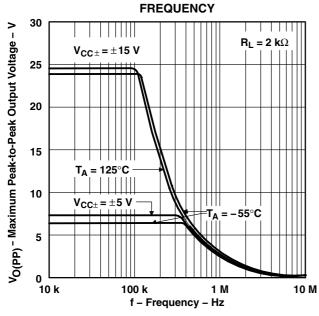


Figure 14

MAXIMUM PEAK-TO-PEAK OUTPUT VOLTAGE

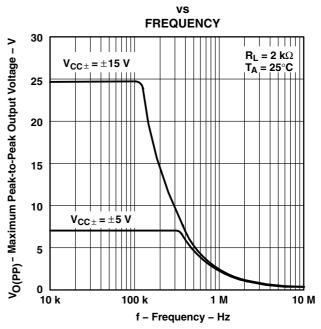
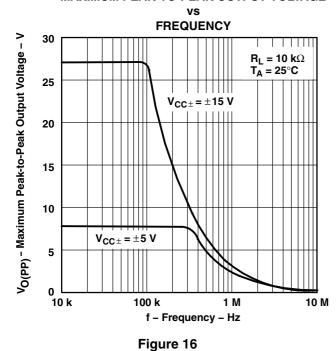
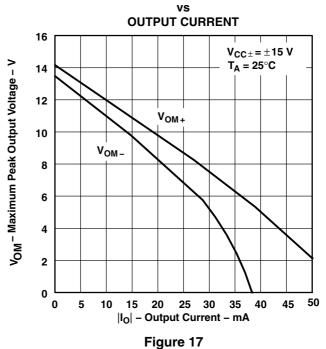


Figure 15

MAXIMUM PEAK-TO-PEAK OUTPUT VOLTAGE



MAXIMUM PEAK OUTPUT VOLTAGE



† Data at high and low temperatures are applicable within the rated operating free-air temperature ranges of the various devices.



MAXIMUM PEAK OUTPUT VOLTAGE FREE-AIR TEMPERATURE 16 $R_L = 10 \text{ k}\Omega$ V_{OM} - Maximum Peak Output Voltage - V 12 $R_L = 2 k\Omega$ V_{OM+} 8 4 $V_{CC\pm} = \pm 15 \text{ V}$ 0 -4 -8 V_{OM} $R_L = 2 k\Omega$ -12 $R_L = 10 \text{ k}\Omega$ -16 -75 -50 25 50 75 100 125 T_A - Free-Air Temperature - °C

Figure 18

LARGE-SIGNAL VOLTAGE AMPLIFICATION **LOAD RESISTANCE** 250 A_{VD} - Differential Voltage Amplification - V/m V $V_0 = \pm 1 V$ T_A = 25°C 200 $V_{CC\pm} = \pm 15 \text{ V}$ 150 $V_{CC\pm} = \pm 5 V$ 100 50 0 0.4 10 100 R_I - Load Resistance - $k\Omega$

LARGE-SIGNAL DIFFERENTIAL VOLTAGE **AMPLIFICATION AND PHASE SHIFT**

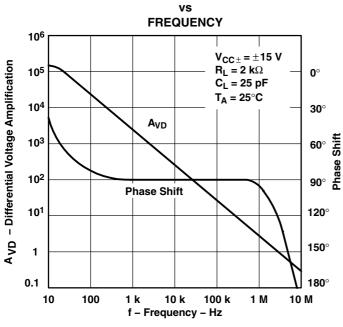


Figure 20

100

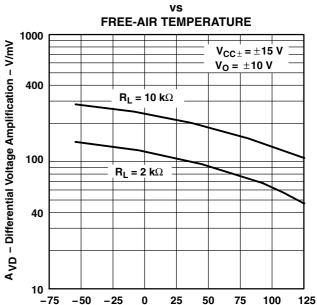


Figure 19

LARGE-SIGNAL VOLTAGE AMPLIFICATION

Figure 21

T_A - Free-Air Temperature - °C

[†] Data at high and low temperatures are applicable within the rated operating free-air temperature ranges of the various devices.

COMMON-MODE REJECTION RATIO FREQUENCY 100 CMRR - Common-Mode Rejection Ratio - dB $V_{CC\pm} = \pm 15 \text{ V}$ 90 T_A = 25°C 80 70 60 50 40 30 20 10 0 100 100 k 10 M 10 10 k 1 M 1 k f - Frequency - Hz

Figure 22

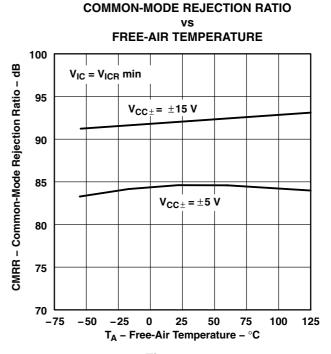


Figure 23

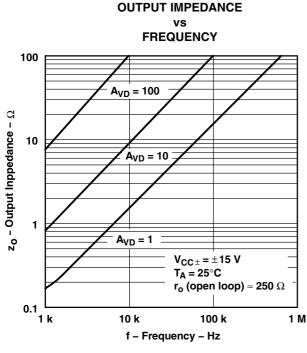


Figure 24

SUPPLY-VOLTAGE REJECTION RATIO

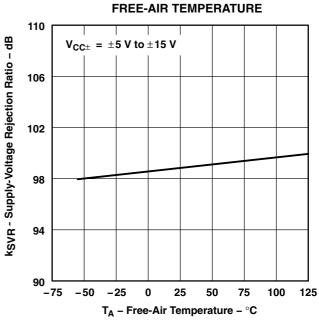
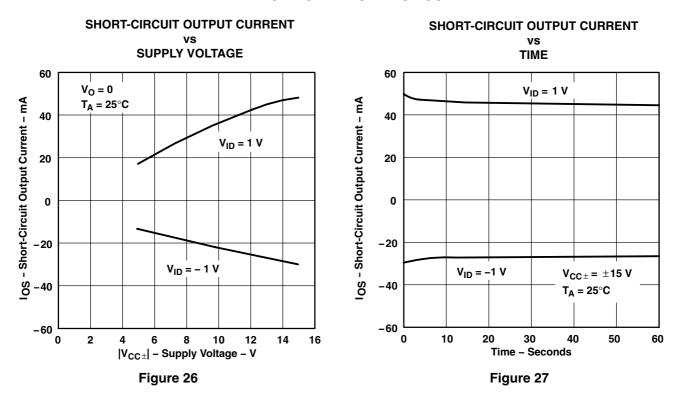


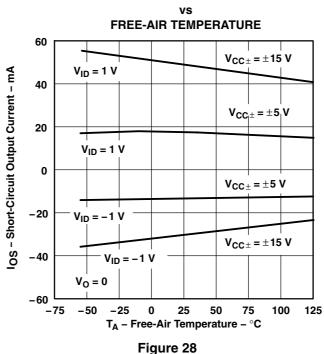
Figure 25

[†] Data at high and low temperatures are applicable within the rated operating free-air temperature ranges of the various devices.



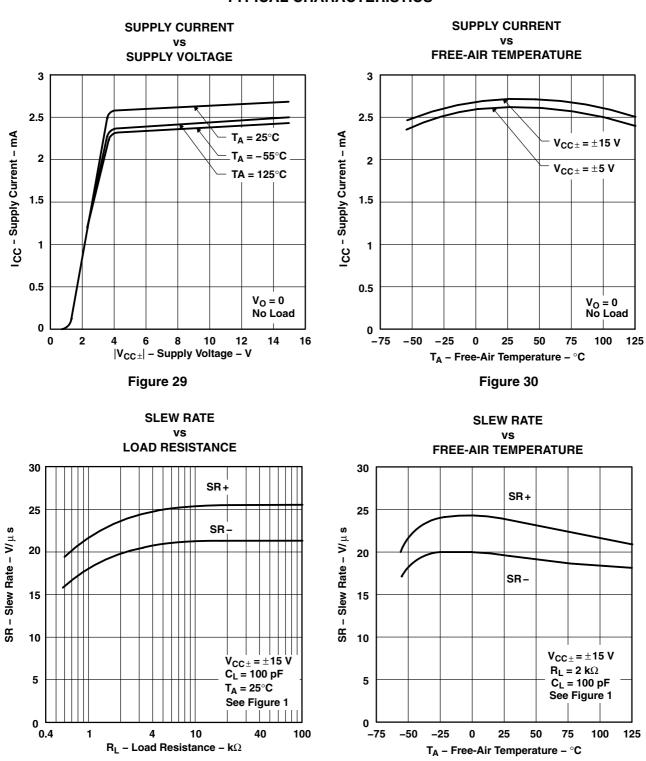


SHORT-CIRCUIT OUTPUT CURRENT



[†] Data at high and low temperatures are applicable within the rated operating free-air temperature ranges of the various devices.





[†] Data at high and low temperatures are applicable within the rated operating free-air temperature ranges of the various devices.

Figure 31



Figure 32

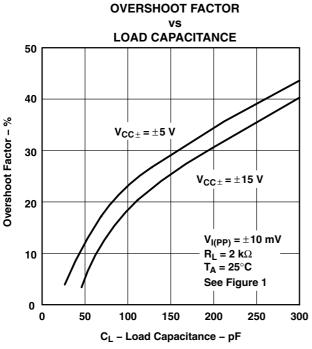


Figure 33

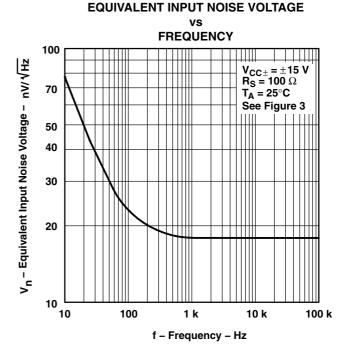
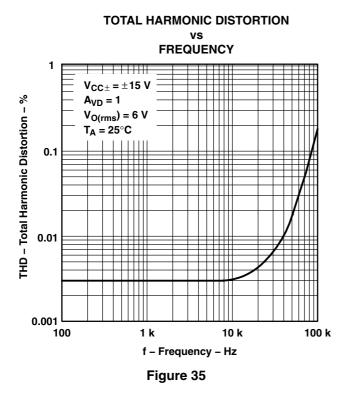
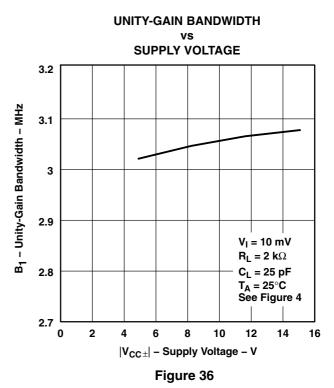


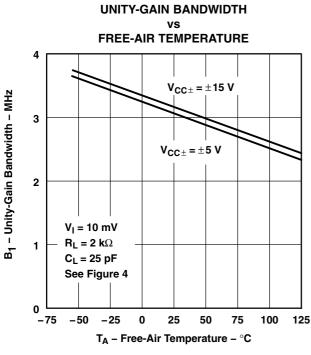
Figure 34

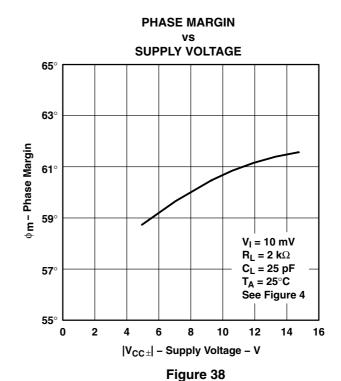




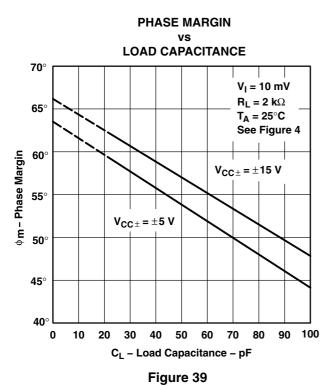
[†] Data at high and low temperatures are applicable within the rated operating free-air temperature ranges of the various devices.

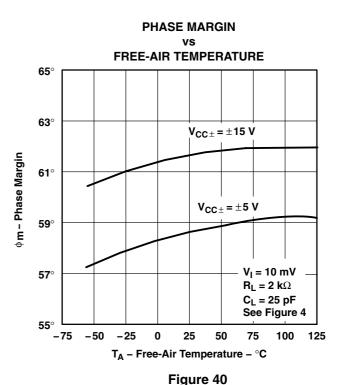
TYPICAL CHARACTERISTICS†











[†] Data at high and low temperatures are applicable within the rated operating free-air temperature ranges of the various devices.



VOLTAGE-FOLLOWER

LARGE-SIGNAL

PULSE RESPONSE

TYPICAL CHARACTERISTICS

8

6

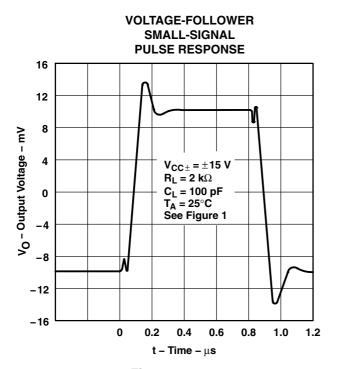


Figure 41

Figure 42

t - Time - μs

6

TYPICAL APPLICATION DATA

output characteristics

All operating characteristics are specified with 100-pF load capacitance. These amplifiers will drive higher capacitive loads; however, as the load capacitance increases, the resulting response pole occurs at lower frequencies, causing ringing, peaking, or even oscillation. The value of the load capacitance at which oscillation occurs varies with production lots. If an application appears to be sensitive to oscillation due to load capacitance, adding a small resistance in series with the load should alleviate the problem. Capacitive loads of 1000 pF, and larger, may be driven if enough resistance is added in series with the output (see Figure 43).

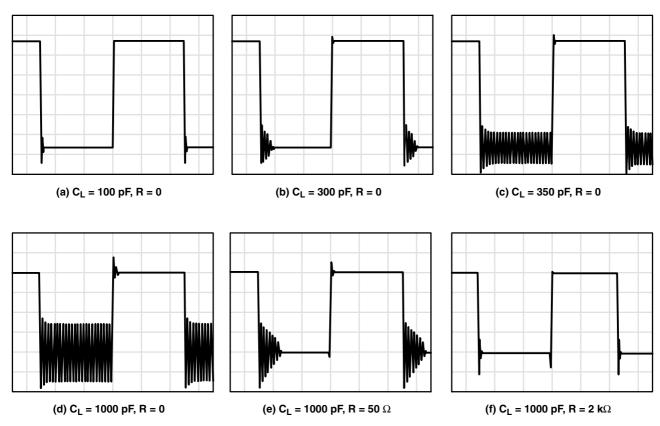


Figure 43. Effect of Capacitive Loads

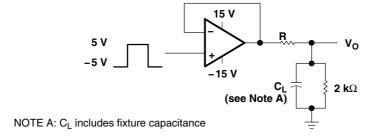


Figure 44. Test Circuit for Output Characteristics



SLOS082B - MARCH 1979 - REVISED - JULY 2004

TYPICAL APPLICATION DATA

input characteristics

These amplifiers are specified with a minimum and a maximum input voltage that, if exceeded at either input, could cause the device to malfunction.

Because of the extremely high input impedance and resulting low bias current requirements, these amplifiers are well suited for low-level signal processing; however, leakage currents on printed circuit boards and sockets easily can exceed bias current requirements and cause degradation in system performance. It is good practice to include guard rings around inputs (see Figure 45). These guards should be driven from a low-impedance source at the same voltage level as the common-mode input.

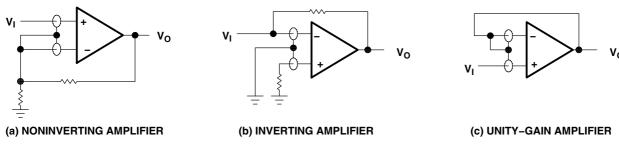


Figure 45. Use of Guard Rings

noise performance

The noise specifications in operational amplifier circuits are greatly dependent on the current in the first-stage differential amplifier. The low input bias current requirements of these amplifiers result in a very low current noise. This feature makes the devices especially favorable over bipolar devices when using values of circuit impedance greater than 50 k Ω .

11-Nov-2025 www.ti.com

PACKAGING INFORMATION

Orderable part number	Status	Material type	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material	MSL rating/ Peak reflow	Op temp (°C)	Part marking (6)
TL288CP	Active	Production	PDIP (P) 8	50 TUBE	Yes	NIPDAU	N/A for Pkg Type	0 to 70	TL288CP
TL288CP.A	Active	Production	PDIP (P) 8	50 TUBE	Yes	NIPDAU	N/A for Pkg Type	0 to 70	TL288CP
TL288CPE4	Active	Production	PDIP (P) 8	50 TUBE	-	Call TI	Call TI	0 to 70	

⁽¹⁾ Status: For more details on status, see our product life cycle.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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⁽²⁾ Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

⁽⁴⁾ Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

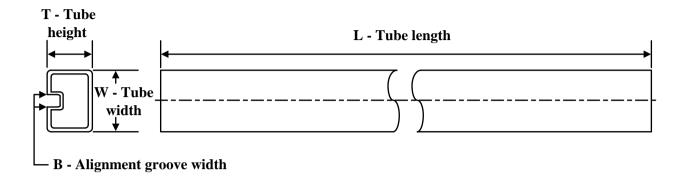
⁽⁵⁾ MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

PACKAGE MATERIALS INFORMATION

www.ti.com 23-May-2025

TUBE



*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
TL288CP	Р	PDIP	8	50	506	13.97	11230	4.32
TL288CP.A	Р	PDIP	8	50	506	13.97	11230	4.32

P (R-PDIP-T8)

PLASTIC DUAL-IN-LINE PACKAGE



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Falls within JEDEC MS-001 variation BA.



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Last updated 10/2025